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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
LI	2025	345/211-214.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 13:15
L2	83,8	analog and L1	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 13:16
L3	89635	TFT or (thin near film near transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:16
L4	267	L2 and L3	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 14:10
L5	37666	nonvolatile near memory	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 13:18
L6	3	L4 and L5	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 13:18
L7	79592	PWM or (pulse near width near modulat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
L8	4170	L7 same (triang\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
L9	73473	"345".clas.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
L10	40	L8 and L9	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
LII	29	L10 and analog	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
L12		L8 and L1 and analog	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:25

L13	18	L4 and L7	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 14:31
L14	1	"20020158590"	US-PGPUB; USPAT; USOCR	OR ,	ON	2006/05/15 14:52
L15	55622	(thin near film) near5 substrate	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 14:59
L16	7443	(inductor or coil) and diode and ((feedback or feed-back or (feed adj back)) near3 voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 14:53
L17	31	L16 and L15	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 14:55
L18	97	L15 and L1	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 15:19
L19	1	"20020044145"	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 15:57
L20	1	"20020145602"	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 16:03
L21	1	"20020175662"	US-PGPUB; USPAT; USOCR	OR .	ON	2006/05/15 16:30
L22	1	"20030011586"	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/15 16:31
SI	7443	(inductor or coil) and diode and ((feedback or feed-back or (feed adj back)) near3 voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:31
S2	25685	FPC or (flexible adj printed adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:32
S3	79558	PWM or (pulse near width near modulat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:35
S4	554900	LCD or (liquid adj crystal)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:34

5/15/2006 5:14:16 PM

S5	156826	EL or (electroluminescent or electro-luminescent or (electro adj luminescent))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:34
S6	4169	S3 same (triang\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:25
S7	73473	"345".clas.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 09:35
S8	216	345/691.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:48
S9	40	S6 and S7	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/15 13:20
S10	2	S1 and S2 and S4 and S5 and regulat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR ·	ON	2006/05/12 10:06
S11	21	S1 and S2 and regulat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 13:04
S12	89548	TFT or (thin near film near transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 10:08
S13	4642	S12 and regulat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:00
S14	26	S13 and S1	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 10:12

S15	106909	regulat\$3 and (voltage same (rais\$3 or lower\$3 or increas\$3 or descreas\$3 or multiply\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:01
S16	2416	S12 and S15	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:01
S17	23	S1 and S16	.US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ОИ	2006/05/12 12:02
S18	23	S17 and S12	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:02
S19	2	"6963323".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 12:19
S20	3	("6127995" "6331844" "6518962").PN. OR ("6963323").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:35
S21	212	S16 and (inductor or coil) and diode and capacitor	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:36
S22	57388	"345".clas.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:36
S23	53	S21 and S22	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:47
S24	2025	345/211-214.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:16
S25	5	S16 and S8	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:48
S26	50	S24 and S16	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:50
S27	3 "	S1 and S26	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:55
S28	381	flyback near3 regulat\$3	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 12:56

S29	1	S28 and "345".clas.	US-PGPUB;	OR	ON	2006/05/12 12:56
			USPAT; USOCR			
S30	2	"20030011586"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 13:08
S31	2	"20030201967"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 13:08
S32	4	S24 and S5 and S4 and S1	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:21
S33	9885	345/76-100.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:21
S34	0	S33 and S1 and S2 and S3 and S4 and S5	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:22
S35	0	S33 and S1 and S2 and S3	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:22
S36	36	S33 and S1	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:25
S37	1409	345/76.ccls.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:26
S38	. 11	S37 and S1	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/12 14:26
S39	21	S9 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 14:35
S40	2	EL and LCD and (memory and pulse) and S39	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 15:08
S41	4	"20020036636" or "20020180721"	US-PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/05/12 15:08